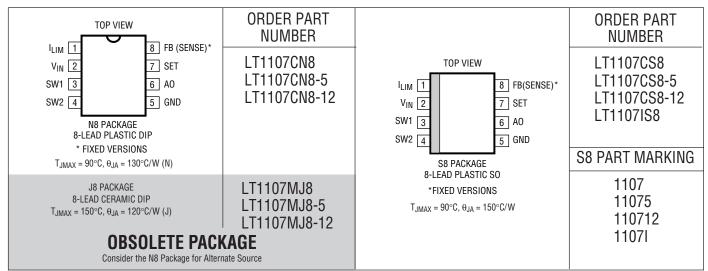
ABSOLUTE MAXIMUM RATINGS (Note 1)

Supply Voltage (V _{IN})	V
SW1 Pin Voltage (V _{SW1}) 50\	V
SW2 Pin Voltage (V _{SW2}) – 0.5V to V _{II}	Ν
Feedback Pin Voltage (LT1107) 5\	V
Sense Pin Voltage (LT1107-5, LT1107-12) 36\	V
Maximum Power Dissipation 500mW	V
Set Pin Voltage 5.5	V

Maximum Switch Current 1.5	5A
Operating Temperature Range	
LT1107C 0°C to 70	°C
_LT1107I –45°C to 85	°C
LT1107M(OBSOLETE)55°C to 125	°C
Storage Temperature Range65°C to 150	°C
Lead Temperature (Soldering, 10 sec) 300	°C

PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, $V_{IN} = 3V$, military or commercial version, $T_A = 25^{\circ}C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS			MIN	ТҮР	MAX	UNITS
IQ	Quiescent Current	Switch OFF				320	450	μA
	Quiescent Current, Step-Up Mode Configuration	No Load	LT1107-5 LT1107-12			360 550		μA μA
V _{IN}	Input Voltage	Step-Up Mode Step-Down Mode		•	2		12.6 30.0	V V
	Comparator Trip Point Voltage	LT1107 (Note 2)		•	1.2	1.25	1.3	V
V _{OUT}	Output Sense Voltage	LT1107-5 (Note 3) LT1107-12 (Note 3)		•	4.75 11.40	5 12	5.25 12.60	V V
	Comparator Hysteresis	LT1107		•		8	12.5	mV
	Output Hysteresis	LT1107-5 LT1107-12		•		32 75	50 120	mV mV
f _{OSC}	Oscillator Frequency				50	63	77	kHz
	Duty Cycle, Step-Up Mode	Full Load			64	70	76	%
t _{ON}	Switch ON Time, Step-Up Mode	$I_{\mbox{LIM}}$ Tied to $V_{\mbox{IN}}$			8.8	11	12.7	μs



ELECTRICAL CHARACTERISTICS The \bullet denotes the specifications which apply over the full operating temperature range, $V_{IN} = 3V$, military or commercial version, $T_A = 25^{\circ}C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
	Feedback Pin Bias Current	LT1107, V _{FB} = 0V			70	120	nA
	Set Pin Bias Current	V _{SET} = V _{REF}	•		70	300	nA
V _{OL}	Gain Block Output Low	I _{SINK} = 300μA, V _{SET} = 1V	•		0.15	0.4	V
	Reference Line Regulation	$5V \le V_{IN} \le 30V$	•		0.02	0.075	%/V
Av	Gain Block Gain	R _L = 100k (Note 4)	•	1000	6000		V/V
	Current Limit	220 Ω to I _{LIM} to V _{IN}			400		mA
	Current Limit Temperature Coefficient		•		-0.3		%/°C
	Switch OFF Leakage Current	Measured at SW1 Pin, V _{SW1} = 12V			1	10	μA
V _{SW2}	Maximum Excursion Below GND	$I_{SW1} \le 10 \mu A$, Switch OFF			-400	-350	mV

The \bullet denotes the specifications which apply over the full operating temperature range, $V_{IN} = 3V$, $-55^{\circ}C \le T_A \le 125^{\circ}C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	LT1107N Typ	MAX	UNITS
l _Q	Quiescent Current	Switch OFF	•			500	μA
f _{OSC}	Oscillator Frequency		•	40	63	95	kHz
DC	Duty Cycle	Step-Up Mode Step-Down Mode, V _{IN} = 12V	•	56 45	69 60	81 73	% %
t _{ON}	Switch ON Time	Step-Up Mode Step-Down Mode, V _{IN} = 12V	•	7 5	11 9	15 13	μs μs
	Reference Line Regulation	$\begin{array}{l} 2V \leq V_{IN} \leq 5V, \ 0^{\circ}C \leq T_A \leq 125^{\circ}C \\ 2.4V \leq V_{IN} \leq 5V, \ T_A = -55^{\circ}C \end{array}$			0.2	0.4 0.8	%/V %/V
V _{SAT}	Switch Saturation Voltage, Step-Up Mode	$0^{\circ}C \le T_A \le 125^{\circ}C$, $I_{SW} = 500mA$ $T_A = -55^{\circ}C$, $I_{SW} = 400mA$			0.5 0.5	0.65 0.65	V V
	Switch Saturation Voltage, Step-Down Mode	$ \begin{array}{l} V_{IN} = 12V, \ I_{SW} = 500 mA \\ 0^\circ C \leq T_A \leq 125^\circ C \\ T_A = -55^\circ C \end{array} $				1.5 2.0	V V

The \bullet denotes the specifications which apply over the full operating temperature range, V_{IN} = 3V, 0°C \leq T_A \leq 70°C, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	LT1107C Typ	MAX	UNITS
IQ	Quiescent Current	Switch OFF	•			450	μA
f _{OSC}	Oscillator Frequency		•	50	63	88	kHz
DC	Duty Cycle	Step-Up Mode Step-Down Mode, V _{IN} = 12V	•	62 50	69 60	78 70	% %
t _{ON}	Switch ON Time	Step-Up Mode Step-Down Mode, V _{IN} = 12V	•	8 6	11 9	13.5 12.0	μs μs
	Reference Line Regulation	$2V \le V_{IN} \le 5V$	•		0.2	0.7	%/V
V _{SAT}	Switch Saturation Voltage, Step-Up Mode Switch Saturation Voltage, Step-Down Mode	V _{IN} = 3V, I _{SW} = 650mA V _{IN} = 12V, I _{SW} = 650mA	•		0.5 1.1	0.65 1.5	V V

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

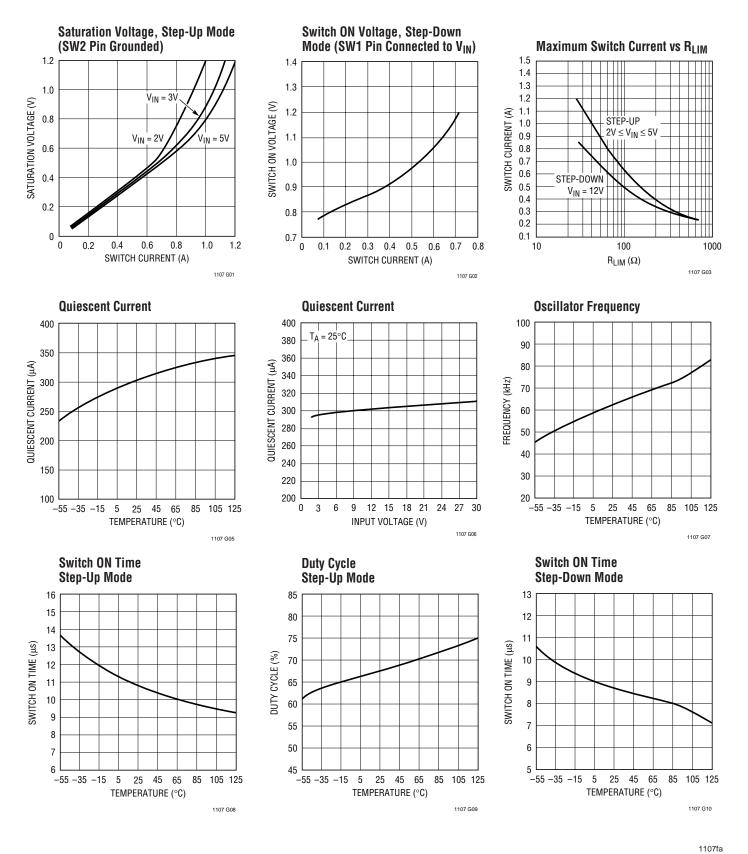
Note 2: This specification guarantees that both the high and low trip points of the comparator fall within the 1.2V to 1.3V range.

Note 3: The output voltage waveform will exhibit a sawtooth shape due to the comparator hysteresis. The output voltage on the fixed-output versions will always be within the specified range.

Note 4: 100k resistor connected between a 5V source and the AO pin.



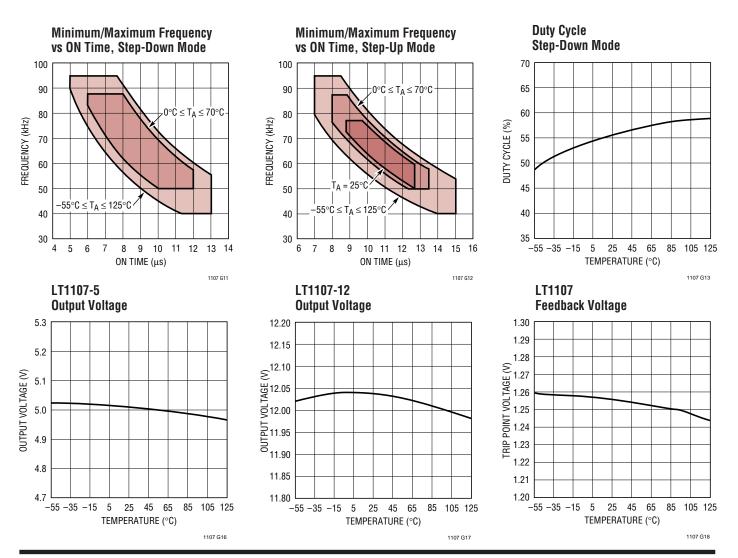
TYPICAL PERFORMANCE CHARACTERISTICS







TYPICAL PERFORMANCE CHARACTERISTICS



PIN FUNCTIONS

 I_{LIM} (Pin 1): Connect this pin to V_{IN} for normal use. Where lower current limit is desired, connect a resistor between I_{LIM} and V_{IN} . A 220 Ω resistor will limit the switch current to approximately 400mA.

VIN (Pin 2): Input Supply Voltage.

SW1~(Pin~3): Collector of Power Transistor. For step-up mode connect to inductor/diode. For step-down mode connect to $V_{IN}.$

SW2 (Pin 4): Emitter of Power Transistor. For step-up mode connect to ground. For step-down mode connect to inductor/diode. This pin must never be allowed to go more than a Schottky diode drop below ground.

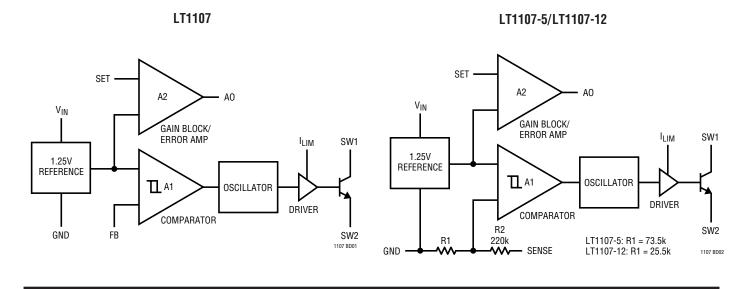
GND (Pin 5): Ground.

AO (Pin 6): Auxiliary Gain Block (GB) Output. Open collector, can sink 300μ A.

SET (Pin 7): GB Input. GB is an op amp with positive input connected to SET pin and negative input connected to 1.25V reference.

FB/SENSE (Pin 8): On the LT1107 (adjustable), this pin goes to the comparator input. On the LT1107-5 and LT1107-12, this pin goes to the internal application resistor that sets output voltage.

BLOCK DIAGRAMS



OPERATION

The LT1107 is a gated oscillator switcher. This type architecture has very low supply current because the switch is cycled when the feedback pin voltage drops below the reference voltage. Circuit operation can best be understood by referring to the LT1107 block diagram. Comparator A1 compares the feedback (FB) pin voltage with the 1.25V reference signal. When FB drops below 1.25V, A1 switches on the 63kHz oscillator. The driver amplifier boosts the signal level to drive the output NPN power switch. The switch cycling action raises the output voltage and FB pin voltage. When the FB voltage is sufficient to trip A1, the oscillator is gated off. A small amount of hysteresis built into A1 ensures loop stability without external frequency compensation. When the comparator output is low, the oscillator and all high current circuitry is turned off, lowering device guiescent current to just 300µA.

The oscillator is set internally for 11µs ON time and 5µs OFF time in step-up mode, optimizing the device for converters where $V_{OUT} \approx 3V_{IN}$. The combination of high duty cycle and the current limit feature enables continuous mode operation in many applications, increasing available output power.

Gain block A2 can serve as a low-battery detector. The negative input of A2 is the 1.25V reference. A resistor divider from V_{IN} to GND, with the mid-point connected to the SET pin provides the trip voltage in a low-battery detector application. A0 can sink $300\mu A$ (use a 22k resistor pull-up to 5V).

A resistor connected between the I_{LIM} pin and V_{IN} sets maximum switch current. When the switch current exceeds the set value, the switch cycle is prematurely terminated. If current limit is not used, I_{LIM} should be tied directly to V_{IN} . Propagation delay through the current limit circuitry is approximately 1µs.

In step-up mode the switch emitter (SW2) is connected to ground and the switch collector (SW1) drives the inductor; in step-down mode the collector is connected to $V_{\rm IN}$ and the emitter drives the inductor.

The LT1107-5 and LT1107-12 are functionally identical to the LT1107. The -5 and -12 versions have on-chip voltage setting resistors for fixed 5V or 12V outputs. Pin 8 on the fixed versions should be connected to the output. No external resistors are needed.



Inductor Selection — Step-Up Converter

In a step-up, or boost converter (Figure 1), power generated by the inductor makes up the difference between input and output. Power required from the inductor is determined by:

$$P_{L} = \left(V_{OUT} + V_{D} - V_{IN(MIN)}\right) \left(I_{OUT}\right)$$
(1)

where V_D is the diode drop (0.5V for a 1N5818 Schottky). Energy required by the inductor per cycle must be equal or greater than:

$$P_L/f_{OSC}$$
 (2)

in order for the converter to regulate the output.

When the switch is closed, current in the inductor builds according to:

$$I_{L}(t) = \frac{V_{IN}}{R'} \left(1 - e^{\frac{-R't}{L}} \right)$$
(3)

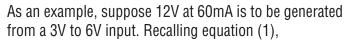
where R' is the sum of the switch equivalent resistance (0.8 Ω typical at 25°C) and the inductor DC resistance. When the drop across the switch is small compared to V_{IN}, the simple lossless equation:

$$I_{L}(t) = \frac{V_{IN}}{L}t$$
(4)

can be used. These equations assume that at t = 0, inductor current is zero. This situation is called "discontinuous mode operation" in switching regulator parlance. Setting "t" to the switch ON time from the LT1107 specification table (typically 11µs) will yield I_{PEAK} for a specific "L" and V_{IN}. Once I_{PEAK} is known, energy in the inductor at the end of the switch ON time can be calculated as:

$$E_{L} = \frac{1}{2} L I_{PEAK}^{2}$$
(5)

 E_L must be greater than P_L/f_{OSC} for the converter to deliver the required power. For best efficiency I_{PEAK} should be kept to 1A or less. Higher switch currents will cause excessive drop across the switch resulting in reduced efficiency. In general, switch current should be held to as low a value as possible in order to keep switch, diode and inductor losses at a minimum.



$$P_{L} = (12V + 0.5V - 3V)(60mA) = 570mW$$
 (6)

Energy required from the inductor is:

$$\frac{P_{L}}{f_{OSC}} = \frac{570 \text{mW}}{63 \text{kHz}} = 9.05 \mu \text{J}$$
(7)

Picking an inductor value of $33\mu H$ with 0.2Ω DCR results in a peak switch current of:

$$I_{PEAK} = \frac{3V}{1\Omega} \left(1 - e^{\frac{-1\Omega \cdot 11\mu s}{33\mu H}} \right) = 850 \text{mA}$$
(8)

Substituting I_{PEAK} into Equation 4 results in:

$$E_{L} = \frac{1}{2} (33\mu H) (0.85A)^{2} = 11.91\mu J$$
(9)

Since 11.9μ J > 9.05μ J, the 33μ H inductor will work. This trial-and-error approach can be used to select the optimum inductor.

A resistor can be added in series with the I_{LIM} pin to invoke switch current limit. The resistor should be picked so the calculated I_{PEAK} at minimum V_{IN} is equal to the Maximum Switch Current (from Typical Performance Characteristic curves). Then, as V_{IN} increases, peak switch current is held constant, resulting in increasing efficiency.

Inductor Selection — Step-Down Converter

The step-down case (Figure 2) differs from the step-up in that the inductor current flows through the load during both the charge and discharge periods of the inductor. Current through the switch should be limited to ~650mA in this mode. Higher current can be obtained by using an external switch (see LT1111 and LT1110 data sheets). The I_{LIM} pin is the key to successful operation over varying inputs.

After establishing output voltage, output current and input voltage range, peak switch current can be calculated by the formula:

$$I_{PEAK} = \frac{2I_{OUT}}{DC} \left[\frac{V_{OUT} + V_D}{V_{IN} - V_{SW} + V_D} \right]$$
(10)



where DC = duty cycle (0.50 in step-down mode)

 V_{SW} = switch drop in step-down mode

 V_D = diode drop (0.5V for a 1N5818)

 I_{OUT} = output current

V_{OUT} = output voltage

V_{IN} = minimum input voltage

 V_{SW} is actually a function of switch current which is in turn a function of V_{IN} , L, time, and V_{OUT} . To simplify, 1.5V can be used for V_{SW} as a very conservative value.

Once IPEAK is known, inductor value can be derived from:

$$L = \frac{V_{IN} (MIN) - V_{SW} - V_{OUT}}{I_{PEAK}} \times t_{ON}$$
(11)

where t_{ON} = switch ON time (7µs).

Next, the current limit resistor R_{LIM} is selected to give I_{PEAK} from the Maximum Switch Current vs R_{LIM} curve. The addition of this resistor keeps maximum switch current constant as the input voltage is increased.

As an example, suppose 5V at 300mA is to be generated from a 12V to 24V input. Recalling Equation (10):

$$I_{PEAK} = \frac{2(300\text{mA})}{0.50} \left[\frac{5+0.5}{12-1.5+0.5} \right] = 600\text{mA} \quad (12)$$

Next, inductor value is calculated using Equation (11):

$$L = \frac{12 - 1.5 - 5}{600 \text{mA}} 7 \mu \text{s} = 64 \mu \text{H}$$
(13)

Use the next lowest standard value (56μ H).

Then pick R_{LIM} from the curve. For I_{PEAK} = 600mA, R_{LIM} = 56 $\Omega.$

Inductor Selection — Positive-to-Negative Converter

Figure 4 shows hookup for positive-to-negative conversion. All of the output power must come from the inductor. In this case,

$$P_{L} = \left(\left| V_{OUT} \right| + V_{D} \right) \left(I_{OUT} \right)$$
(14)

In this mode the switch is arranged in common collector or step-down mode. The switch drop can be modeled as a 0.75V source in series with a 0.65Ω resistor. When the switch closes, current in the inductor builds according to:

$$I_{L}(t) = \frac{V_{L}}{R'} \left(1 - e^{\frac{-R't}{L}} \right)$$
(15)

where R' = 0.65 Ω + DCRL $V_L = V_{IN} - 0.75V$

As an example, suppose –5V at 50mA is to be generated from a 4.5V to 5.5V input. Recalling Equation (14),

$$P_{L} = (|-5V| + 0.5V)(50mA) = 275mW$$
 (16)

Energy required from the inductor is:

$$\frac{P_{L}}{f_{OSC}} = \frac{275 \text{mW}}{63 \text{kHz}} = 4.4 \mu \text{J}$$
(17)

Picking an inductor value of $100\mu H$ with 0.2Ω DCR results in a peak switch current of:

$$I_{\text{PEAK}} = \frac{\left(4.5\text{V} - 0.75\text{V}\right)}{\left(0.65\Omega + 0.2\Omega\right)} \left(1 - e^{\frac{-0.85\Omega \cdot 9\mu\text{s}}{100\mu\text{H}}}\right)$$
$$= 325\text{mA} \tag{18}$$

Substituting I_{PEAK} into Equation (04) results in:

$$E_{L} = \frac{1}{2} (100 \mu H) (0.325 A)^{2} = 5.28 \mu J$$
 (19)

Since $5.28\mu J > 3.82\mu J$, the $100\mu H$ inductor will work.

With this relatively small input range, R_{LIM} is not usually necessary and the I_{LIM} pin can be tied directly to V_{IN} . As in the step-down case, peak switch current should be limited to ~650mA.

Step-Up (Boost Mode) Operation

A step-up DC/DC converter delivers an output voltage higher than the input voltage. Step-up converters are *not* short-circuit protected since there is a DC path from input to output.



The usual step-up configuration for the LT1107 is shown in Figure 1. The LT1107 first pulls SW1 low causing $V_{IN} - V_{CESAT}$ to appear across L1. A current then builds up in L1. At the end of the switch ON time the current in L1 is¹:

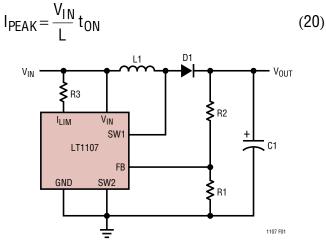


Figure 1. Step-Up Mode Hookup

Immediately after switch turn-off, the SW1 voltage pin starts to rise because current cannot instantaneously stop flowing in L1. When the voltage reaches $V_{OUT} + V_D$, the inductor current flows through D1 into C1, increasing V_{OUT} . This action is repeated as needed by the LT1107 to keep V_{FB} at the internal reference voltage of 1.25V. R1 and R2 set the output voltage according to the formula:

$$V_{OUT} = \left(1 + \frac{R^2}{R^1}\right) \left(1.25V\right) \tag{21}$$

Step-Down (Buck Mode) Operation

A step-down DC/DC converter converts a higher voltage to a lower voltage. The usual hookup for an LT1107 based step-down converter is shown in Figure 2.

When the switch turns on, SW2 pulls up to $V_{IN}-V_{SW}$. This puts a voltage across L1 equal to $V_{IN}-V_{SW}-V_{OUT}$, causing a current to build up in L1. At the end of the switch ON time, the current in L1 is equal to:

$$I_{PEAK} = \frac{V_{IN} - V_{SW} - V_{OUT}}{L} t_{ON}$$
(22)

Note 1: This simple expression neglects the effects of switch and coil resistance. This is taken into account in the "Inductor Selection" section.



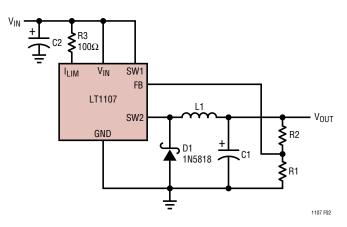


Figure 2. Step-Down Mode Hookup

When the switch turns off, the SW2 pin falls rapidly and actually goes below ground. D1 turns on when SW2 reaches 0.4V below ground. D1 MUST BE A SCHOTTKY DIODE. The voltage at SW2 must never be allowed to go below -0.5V. A silicon diode such as the 1N4933 will allow SW2 to go to -0.8V, causing potentially destructive power dissipation inside the LT1107. Output voltage is determined by:

$$V_{OUT} = \left(1 + \frac{R^2}{R^1}\right) \left(1.25V\right)$$
(23)

R3 programs switch current limit. This is especially important in applications where the input varies over a wide range. Without R3, the switch stays on for a fixed time each cycle. Under certain conditions the current in L1 can build up to excessive levels, exceeding the switch rating and/or saturating the inductor. The 100Ω resistor programs the switch to turn off when the current reaches approximately 700mA. When using the LT1107 in stepdown mode, output voltage should be limited to 6.2V or less. Higher output voltages can be accommodated by inserting a 1N5818 diode in series with the SW2 pin (anode connected to SW2).

Inverting Configurations

The LT1107 can be configured as a positive-to-negative converter (Figure 3), or a negative-to-positive converter (Figure 4). In Figure 3, the arrangement is very similar to a step-down, except that the high side of the feedback is referred to ground. This level shifts the output negative. As in the step-down mode, D1 must be a Schottky diode, and

 $|V_{OUT}|$ should be less than 6.2V. More negative output voltages can be accommodated as in the prior section.

In Figure 4, the input is negative while the output is positive. In this configuration, the magnitude of the input voltage can be higher or lower than the output voltage. A level shift, provided by the PNP transistor, supplies proper polarity feedback information to the regulator.

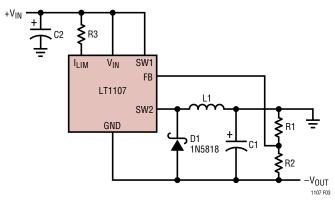


Figure 3. Positive-to-Negative Converter

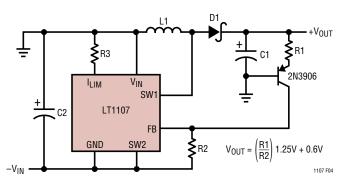


Figure 4. Negative-to-Positive Converter

Using the $I_{\mbox{\scriptsize LIM}}$ Pin

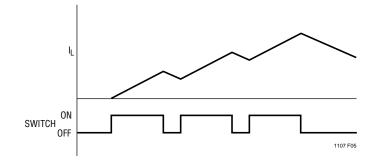
The LT1107 switch can be programmed to turn off at a set switch current, a feature not found on competing devices. This enables the input to vary over a wide range without exceeding the maximum switch rating or saturating the inductor. Consider the case where analysis shows the LT1107 must operate at an 800mA peak switch current with a 2V input. If V_{IN} rises to 4V, the peak switch current will rise to 1.6A, exceeding the maximum switch current rating. With the proper resistor selected (see the "Maximum Switch Current vs R_{LIM}" characteristic), the switch current will be limited to 800mA, even if the input voltage increases.

Another situation where the I_{LIM} feature is useful occurs when the device goes into continuous mode operation. This occurs in step-up mode when:

$$\frac{V_{OUT} + V_{DIODE}}{V_{IN} - V_{SW}} < \frac{1}{1 - DC}$$
(24)

When the input and output voltages satisfy this relationship, inductor current does not go to zero during the switch OFF time. When the switch turns on again, the current ramp starts from the non-zero current level in the inductor just prior to switch turn-on. As shown in Figure 5, the inductor current increases to a high level before the comparator turns off the oscillator. This high current can cause excessive output ripple and requires oversizing the output capacitor and inductor. With the I_{LIM} feature, the switch turns off at the programmed current as shown in Figure 6, keeping output ripple to a minimum.







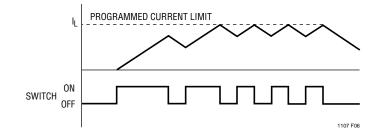


Figure 6. Current Limit Keeps Inductor Current Under Control



Figure 7 details current limit circuitry. Sense transistor A1, whose base and emitter are paralleled with power switch Q2, is ratioed such that approximately 0.5% of Q2's collector current flows in Q1's collector. This current is passed through internal 80Ω resistor R1 and out through the I_{LIM} pin. The value of the external resistor connected between I_{LIM} and V_{IN} sets the current limit. When sufficient switch current flows to develop a V_{BE} across R1 + R_{LIM}, Q3 turns on and injects current into the oscillator, turning off the switch. Delay through this circuitry is approximately 800ns. The current trip point becomes less accurate for switch ON times less than 3µs. Resistor values programming switch ON time for 800ns or less will cause spurious response in the switch circuitry although the device will still maintain output regulation.

Using the Gain Block

The gain block (GB) on the LT1107 can be used as an error amplifier, low-battery detector or linear post regulator. The gain block itself is a very simple PNP input op amp with an open collector NPN output. The negative input of the gain block is tied internally to the 1.25V reference. The positive input comes out on the SET pin.

Arrangement of the gain block as a low-battery detector is straightforward. Figure 8 shows hookup. R1 and R2 need only be low enough in value so that the bias current of the SET input does not cause large errors. 33k for R2 is adequate. R3 can be added to introduce a small amount of hysteresis. This will cause the gain block to "snap" when the trip point is reached. Values in the 1M to 10M range are optimal. The addition of R3 will change the trip point, however.

Output ripple of the LT1107, normally 50mV at $5V_{OUT}$ can be reduced significantly by placing the gain block in front of the FB input as shown in Figure 9. This effectively reduces the comparator hysteresis by the gain of the gain block. Output ripple can be reduced to just a few millivolts using this technique. Ripple reduction works with stepdown or inverting modes as well. For this technique to be effective, output capacitor C1 must be large, so that each switching cycle increases V_{OUT} by only a few millivolts. 1000µF is a good starting value. C1 should be a low ESR type as well.

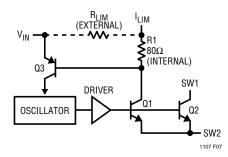


Figure 7. LT1107 Current Limit Circuitry

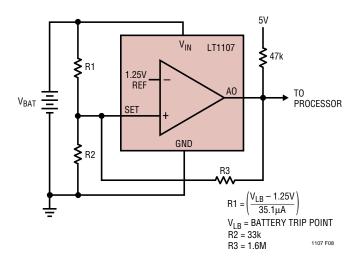
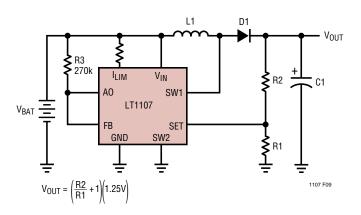


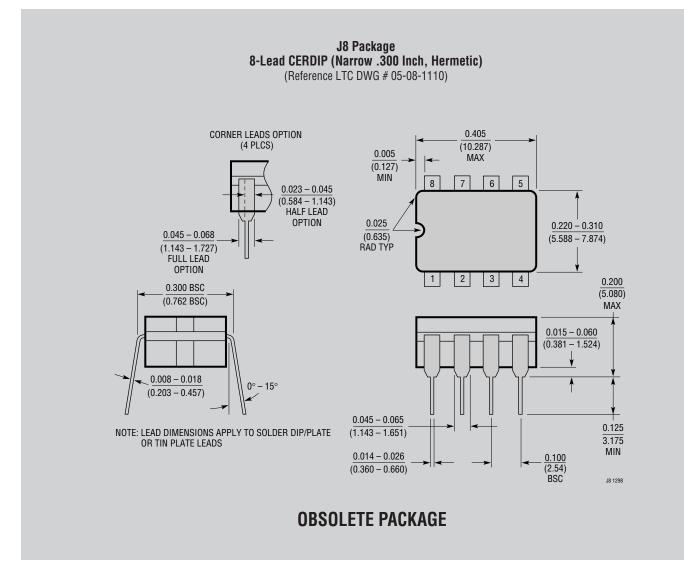
Figure 8. Setting Low-Battery Detector Trip Point







PACKAGE DESCRIPTION





PACKAGE DESCRIPTION

.400* (10.160) MAX 5 8 7 6 $.255 \pm .015^{*}$ $(\overline{6.477\pm0.381})$ 1 2 4 3 $.130\pm.005$ $({.045 - .065 \over (1.143 - 1.651)})$.300 – .325 $(\overline{3.302\pm0.127})$ (7.620 - 8.255).065 (1.651) .009 – .015 TYP ٨ .125 $(\overline{0.229 - 0.381})$.020 (3.175) .325 ^{+.035} -.015 MIN (0.508) MIN <u>.100</u> (2.54) BSC .018 ± .003 (8.255^{+0.889} -0.381) $(\overline{0.457 \pm 0.076})$ N8 0502

N8 Package 8-Lead PDIP (Narrow .300 Inch) (Reference LTC DWG # 05-08-1510)

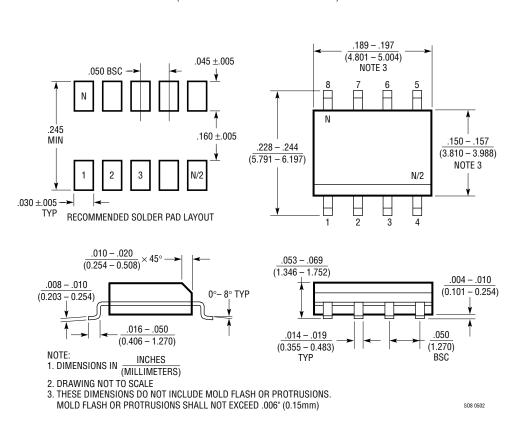
NOTE: NOTE: 1. DIMENSIONS ARE <u>INCHES</u> MILLIMETERS

*THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED .010 INCH (0.254mm)



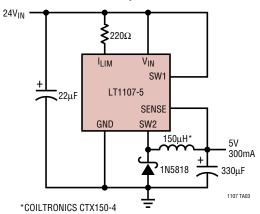
PACKAGE DESCRIPTION



S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)



TYPICAL APPLICATION



24V-to-5V Step-Down Converter

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS			
LT1070/LT1070HV	5A I _{SW} , 40kHz, High Efficiency Switching Regulator	V_{IN} = 3V to 40V/60V, V_{OUT} = 65V/75V, I_Q = 6mA, I_{SD} = <50µA, Can be Used for Buck, Boost, Inverting Applications, TO220-5 Packages			
LT1071/LT1071HV	2.5A I _{SW} , 40kHz, High Efficiency Switching Regulator	V_{IN} = 3V to 40V/60V, V_{OUT} = 65V/75V, I_Q = 6mA, I_{SD} = <50µA, Can be Used for Buck, Boost, Inverting Applications, TO220-5 Package			
LT1072/LT1072HV	1.25A I _{SW} , 40kHz, High Efficiency Switching Regulator	$V_{\rm IN}$ = 3V to 40V/60V, $V_{\rm OUT}$ = 65V/75V, $I_{\rm Q}$ = 6mA, $I_{\rm SD}$ = <50µA, Can be Used for Buck, Boost, Inverting Applications, N8, S8, S16, T0220-5 Packages			
LT1082	1A I _{SW} , 60kHz, High Efficiency Switching Regulator	V_{IN} = 3V to 75V, V_{OUT} = 100V, I_Q = 4.5mA, I_{SD} = <120 μ A, Can be Used for Buck, Boost, Inverting Applications, DD, N8, T0220-5 Packages			
LT1111	1A I _{SW} , 72kHz, High Efficiency Switching Regulator	V_{IN} = 2V to 30V, V_{OUT} = 34V, I_Q = 300µA, Can be Used for Buck, Boost, Inverting Applications, N8, S8 Packages			
LT1170/LT1170HV	5A I _{SW} , 100kHz, High Efficiency Switching Regulator	V _{IN} = 3V to 40V/60V, V _{OUT} = 65V/75V, I _Q = 6mA, I _{SD} = <50µA, Can be Used Buck, Boost, Inverting Applications, DD, N8, S16, T0220-5 Packages			
LT1171/LT1171HV	2.5A I _{SW} , 100kHz, High Efficiency Switching Regulator	V_{IN} = 3V to 40V/60V, V_{OUT} = 65V/75V, I_Q = 6mA, I_{SD} = <50µA, Can be Used for Buck, Boost, Inverting Applications, DD, N8, S16, T0220-5 Packages			
LT1172/LT1172HV	1.25A I _{SW} , 100kHz, High Efficiency Switching Regulator	V_{IN} = 3V to 40V/60V, V_{OUT} = 65V/75V, I_Q = 6mA, I_{SD} = <100µA, Can be Used fo Buck, Boost, Inverting Applications, N8, S16, DD, T0220-5 Packages			
LT1307/LT1307B	600mA I _{SW} , 600kHz, High Efficiency Step-Up Switching Regulator	V_{IN} = 1V to 12V, V_{OUT} = 28V, I_Q = 50µA/1mA, I_{SD} = <1µA Ideal for Single Cell Applications, Low Battery Detect, MS8, N8, S8 Packages			
LT1317/LT1317B	660mA I _{SW} , 600kHz, High Efficiency Step-Up Switching Regulator	V_{IN} = 1.5V to 12V, V_{OUT} = 28V, I_Q = 100µA/4.8mA, I_{SD} = <30µA/28µA Low Battery Detect, MS8, S8 Packages			
LT1370/LT1370HV	6A I _{SW} , 500kHz, High Efficiency Switching Regulator	V_{IN} = 2.7V to 30V, V_{OUT} = 35V/42V, I_Q = 4.5mA, I_{SD} = <12µA, Can be Used for Buck, Boost, Inverting Applications, DD, T0220-7 Packages			
LT1371/LT1371HV	3A I _{SW} , 500kHz, High Efficiency Switching Regulator	$V_{\rm IN}$ = 2.7V to 30V, V_{OUT} = 35V/42V, I_Q = 4mA, I_{SD} = <12µA, Can be Used for Buck, Boost, Inverting Applications, S20, DD, T0220-7 Packages			